

WAS7223Q

USB High speed (480Mbps), DPDT Analog Switch

Descriptions

The WAS7223Q is a high performance, double pole double throw (DPDT) CMOS analog switch that operates from a single +2.3V to +4.5V power supply.

The WAS7223Q is designed for switching of high-speed USB2.0 signals in handset and consumer applications, such as cell phones, digital cameras, and notebooks with hubs or controllers with limited USB I/Os.

The WAS7223Q has low bit-to-bit skew and high channel-to-channel noise isolation, and is compatible with various standards, such as high-speed USB 2.0 (480Mbps). Each switch is bi-directional and offers little attenuation of the high-speed signals at the outputs. Its bandwidth is quite marginal to pass high-speed USB 2.0 differential signals (480Mbps) with good signal integrity.

The WAS7223Q is featured with special circuitry on the D+/D-, which allows the device to withstand a VBUS short to D+ or D- when the USB devices are either powered off or on.

The SEL/OE pin has overvoltage protection that allows voltages above VCC, up to 7.0V to be present on the pin without damage or disruption of operation of the part, regardless of the operating voltage. The WAS7223Q is also featured with smart circuitry to minimize VCC leakage current even when SEL/OE control voltage is lower than VCC supply voltage. In other word, there is no need of additional device to shift SEL/OE level to be the same as that of VCC in real application.

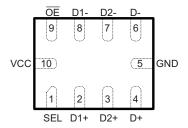
The WAS7223Q is available in QFN2116-10L package. Standard products are Pb-Free and Halogen-Free.

Applications

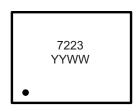
- Cell phones
- MID
- Router
- Other electronics equipments

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Pin configuration (Top view)



Marking

7223 = Device code

YY = Year WW = Week

Order information

Device	Package	Shipping	
WAS7223Q-10/TR	QFN2116-10L	3000/Reel&Tape	

Features

Supply voltage : 2.3 ~ 4.5V

-3dB Bandwidth : 550MHz @ C_L=5pF
Off isolation : -36dB @ 250MHz
Crosstalk : -47dB @ 250MHz

Low quiescent current : <1uA



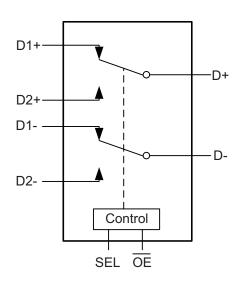
Pin descriptions

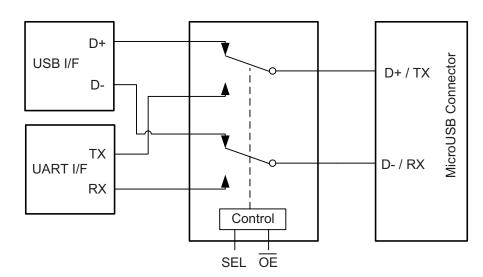
Pin Number	Symbol	Descriptions
1	SEL	Switch select pin, digital logic low or high.
2	D1+	Port A data 1 terminal, normally closed
3	D2+	Port A data 2 terminal, normally open
4	D+	Port A common data terminal, Connect to D1+ or D2+ according to SEL logic
5	GND	Ground
6	D-	Port B common data terminal, Connect to D1- or D2- according to SEL logic
7	D2-	Port B data 2 terminal, normally open
8	D1-	Port B data 1 terminal, normally closed
9	ŌĒ	Enable control, Active low
10	VCC	Power supply

Function descriptions

SEL	ŌĒ	Function
X	Н	Bus switch disconnected
L	L	D+ connect to D1+ and D- connect to D1-
Н	L	D+ connect to D2+ and D- connect to D2-

Logic symbol and typical applications





Logic Symbol

Typical Applications



Absolute maximum ratings

Parameter	Symbol	Value	Unit
Supply voltage range	VCC	-0.5 ~ 6.5	V
Data input/output voltage range	V_{DATA}	-0.5 ~ 6.5	V
Select input voltage range	V_{SEL}	-0.5 ~ 6.5	V
Continues output current	I _{оит}	±50	mA
Junction temperature range	TJ	150	°C
Lead temperature range	T _L	260	°C
Storage temperature range	T _{STG}	-65 ~ 150	°C
Thermal resistance	$R_{ heta JA}$	250	°C/W
ESD protection (HPM)	I/O to VCC, I/O to GND	±7000	V
ESD protection (HBM)	I/O to I/O	±5000	V

Recommend operating ratings

Parameter	Symbol	Value	Unit
Supply voltage range	VCC	2.3 ~ 4.5	V
Data input/output voltage range	V_{DATA}	0.0 ~ VCC	V
Select input voltage range	V_{SEL}	0.0 ~ VCC	V
Enable control input voltage range	V _{OE}	0.0 ~ VCC	V
Operating temperature range	T_A	-40 ~ 85	°C

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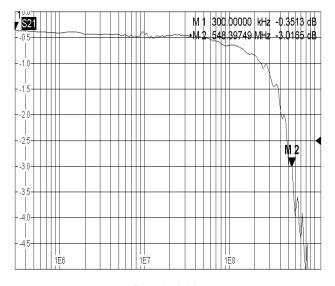


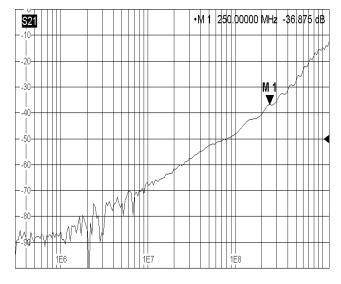
Electronics Characteristics (Ta=25°C, VCC=4.5V, unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit	
Soloet and OE logic high lovel	V	VCC=3.0∼4.5	1.7			V	
Select and OE logic high level	V _{IH}	VCC=2.3~3.0	1.4			V	
Salast and OF lagis law level	\/	VCC=3.0~4.5			0.6	V	
Select and OE logic low level	V _{IL}	VCC=2.3~3.0			0.4	V	
		I _{OUT} =0,					
Supply guide cent current		V _{SEL} >1.5V or			4.0		
Supply quiescent current	I _{CC}	V _{SEL} <0.7V			1.0	uA	
		Refer to figure1					
Select input leakage current	I _{SEL}	V _{SEL} =VCC			±1.0	uA	
Off state switch leakage current	I _{OFF}	See figure 2			±1.0	uA	
On state switch leakage current	I _{ON}	See figure 3			±1.0	uA	
		VCC=3.0V,			7.5		
On-Resistance	D	V _{DATA} =0~0.4V,		5.0		Ω	
On-Resistance	R _{ON}	I _{OUT} =8mA,		5.0			
		See figure 4					
		VCC=3.0V,			0.00		
On Desistance metab	, D	V _{DATA} =0~0.4V,	0.15	0.45			
On-Resistance match	ΔR _{ON}	I _{OUT} =8mA,		0.15	0.20	Ω	
		See figure 4					
		VCC=3.0V,		1.8	2.2	Ω	
On Desigtance flatness	R _{FLAT(ON)}	V _{DATA} =0~1.0V,					
On-Resistance flatness		I _{OUT} =8mA,					
		See figure 4					
Drangation delay time	т /т	C _L =10pF, R _L =50Ω	0.3	0.3	1.2	no	
Propagation delay time	T _{PLH} / T _{PHL}	See figure 5		0.3		ns	
Calcat input to awitch on time	т	C_L =10pF, R_L =50 Ω	75		120	nc	
Select input to switch on time	T _{ON}	See figure 6		/5	120	ns	
Select input to switch off time	T _{OFF}	C_L =10pF, R_L =50 Ω		40	80	no	
Select input to switch on time		See figure 6		40		ns	
Break-Before-Make time	T _{BBM}	Generated by design	0.5			ns	
-3dB Bandwidth	D\A/	$R_L=50\Omega$, $C_L=5pF$		550		MUZ	
-3dB Bandwidth	BW	$R_L=50\Omega$, $C_L=0pF$		800		MHz	
Off isolation	OIRR	R_L =50 Ω , F=250MHz		-36		dB	
Crosstalk	Xtalk	R_L =50 Ω , F=250MHz		-47		dB	
Charge injection	0~	C _L =0.1nF, VCC=3.3V		F		-0	
(Select input to common I/O)	Qg	$R_G=0\Omega$, $V_G=GND$		5		pC	
Select pin input capacitance	C _{IN}	VCC=0V		5		pF	
D1n, D2n,Dn Off capacitance	C _{OFF}	VCC=3.3V, OE =3.3V		5		pF	
D1n, D2n,Dn On capacitance	C _{ON}	VCC=3.3V, OE=0V		6.5		pF	



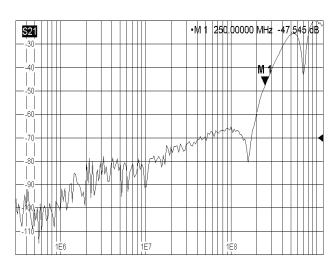
Typical Characteristics (Ta=25°C, VCC=4.5V, unless otherwise noted)

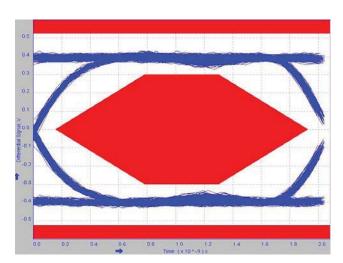




Bandwidth







Crosstalk

Eye Diagram (480Mbps)

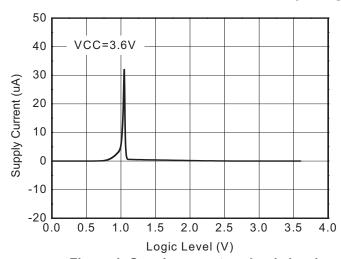
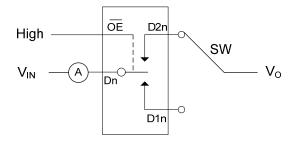


Figure 1: Supply current vs. Logic level

Test Circuit



Conditions: V_{IN}=4.5V, VO=GND

Low SEL D2n Vo

Conditions: V_{IN} =4.5V, V_{O} =Open

Figure 3: On state switch leakage current

Figure 2: Off state switch leakage current

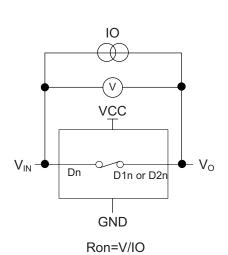


Figure 4: On-Resistance

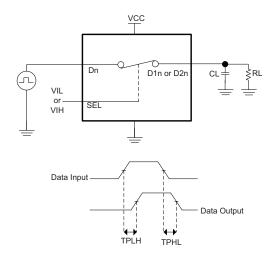
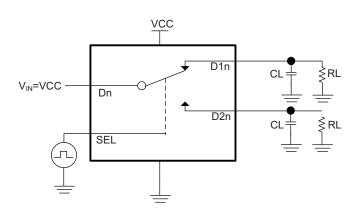


Figure 5: Propagation delay time



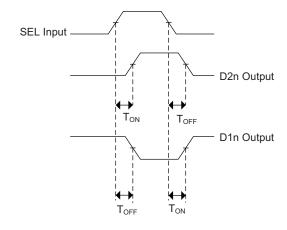
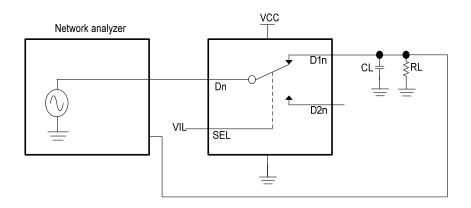


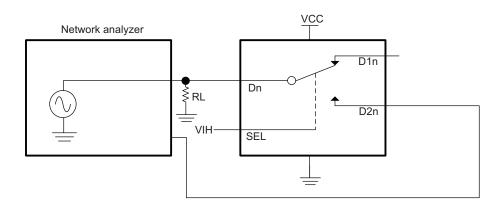
Figure 6: Select input to switch on/off time

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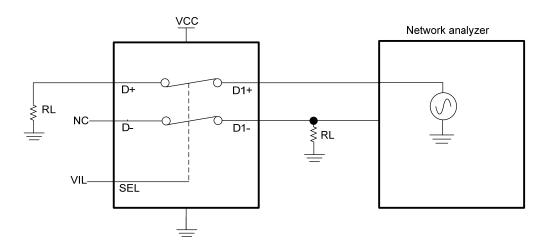




Bandwidth (BW)



Off isolation (OIRR)



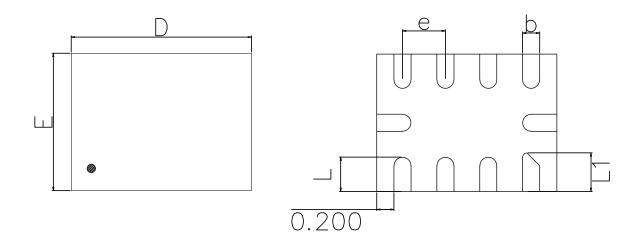
Crosstalk (Xtalk)

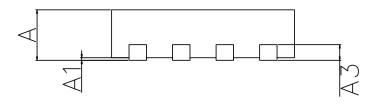
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Package outline dimensions

QFN2116-10L





Symbol	Dimension in Millimeters			
	Min.	Тур.	Max.	
A	0.500	0.550	0.600	
A1	0.000		0.050	
A3	0.150 Ref.			
D	2.050	2.100	2.150	
Е	1.550	1.600	1.650	
b	0.150	0.200	0.250	
е	0.500 (BSC)			
L	0.350	0.400	0.450	
L1	0.450	0.450	0.550	